

DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
50V	1.6Ω @ V _{GS} = 10V	360mA
507	2.5Ω @ V _{GS} = 4.5V	250mA

Description and Applications

This new generation MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc

Features and Benefits

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- ESD Protected to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMN53D0LDWQ</u>)

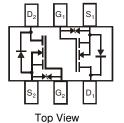
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208(3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)





Top View



Internal Schematic

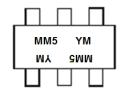
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN53D0LDW-7	SOT363	3000/Tape & Reel
DMN53D0LDW-13	SOT363	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MM5 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2014		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	В			J	K	L	М	N	0	Р	R	S
				_				_	_			
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Characteristic	Symbol	Value	Unit
Drain Source Voltage	VDSS	50	V
Gate-Source Voltage	Vgss	±20	V
Drain Current (Note 5)	I _D	360	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	310	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	411	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

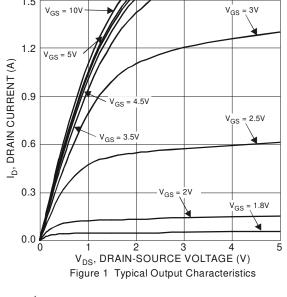
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

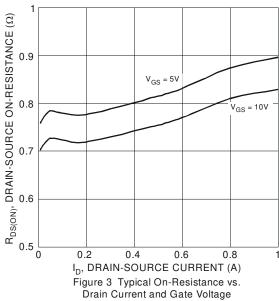
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	Cymbol		i yp	Wax	Onit	rest contaition	
Drain-Source Breakdown Voltage	BV _{DSS}	50	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	loss	_	_	1.0	μΑ	V _{DS} = 50V, V _{GS} = 0V	
Gate-Body Leakage	Igss	_	_	10	μΑ	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)					•		
Gate Threshold Voltage	V _{GS(TH)}	0.8	_	1.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Rds(on)	_ _ _	1.0 1.0 1.4	1.6 2.5 4.5	Ω	$V_{GS} = 10V, I_D = 500mA$ $V_{GS} = 4.5V, I_D = 200mA$ $V_{GS} = 2.5V, I_D = 100mA$	
Source-Drain Diode Forward Voltage	V _{SD}	_	0.8	1.4	V	Vgs = 0V, Is = 500mA	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	46	_	pF		
Output Capacitance	Coss	_	5.3		pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	4.0	_	pF	1 = 1.000112	
Total Gate Charge	Qg	_	0.6	_	nC	151/1/	
Gate-Source Charge	Q_{gs}	_	0.2	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 250mA$	
Gate-Drain Charge	Q_{gd}	_	0.1	_	nC	ID = ZOUIIA	
Turn-On Delay Time	tD(ON)	_	2.7	_	ns		
Turn-On Rise Time	tr	_	2.5	_	ns	V _{DD} = 30V, V _{GS} = 10V,	
Turn-Off Delay Time	tD(OFF)	_	19	_	ns	$R_G = 25\Omega, I_D = 200 \text{mA}$	
Turn-Off Fall Time	tF	_	11	_	ns		

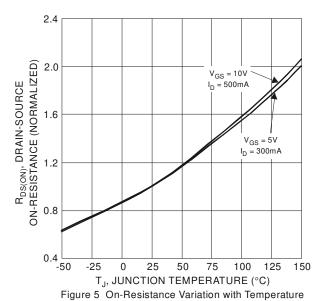
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

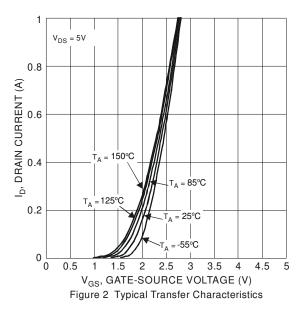
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

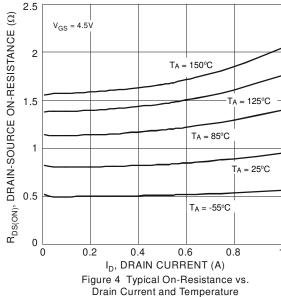


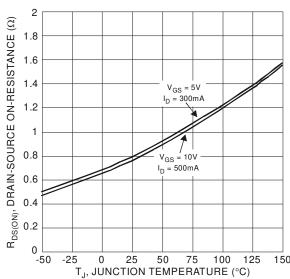














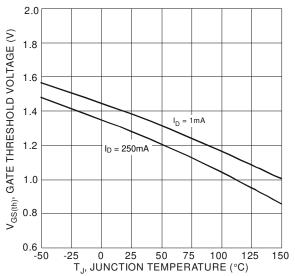
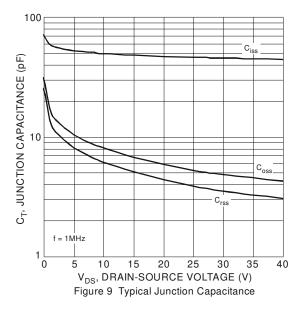
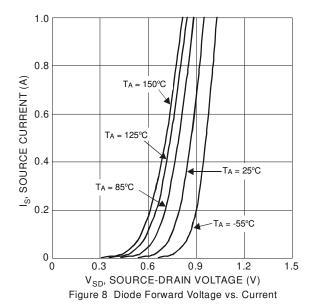
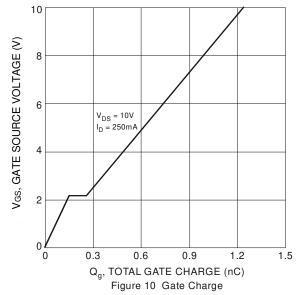


Figure 7 Gate Threshold Variation vs. Ambient Temperature



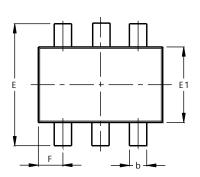


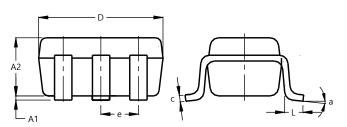




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





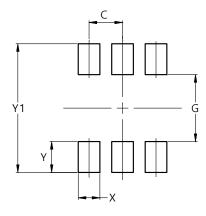
	SOT363					
Dim	Min	Max	Тур			
A 1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
С	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT363

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2.500

July 2021



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